MBR10H100CT, MBRF10H100CT, MBRB10H100CT

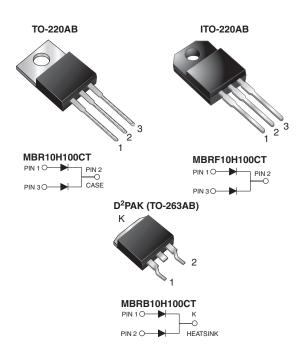


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Dual Common Cathode High Voltage Schottky Rectifier

High Barrier Technology for Improved High Temperature Performance



DESIGN SUPPORT TOOLS

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| PRIMARY CHARACTERISTICS | | | | | | |
|-------------------------|--|--|--|--|--|--|
| I _{F(AV)} | 2 x 5 A | | | | | |
| V_{RRM} | 100 V | | | | | |
| I _{FSM} | 150 A | | | | | |
| V _F | 0.61 V | | | | | |
| I _R | 3.5 μΑ | | | | | |
| T _J max. | 175 °C | | | | | |
| Package | TO-220AC, ITO-220AC, D ² PAK (TO-263AB) | | | | | |
| Circuit configurations | Common cathode | | | | | |

FEATURES

Power pack





- Low power loss, high efficiency
- Low forward voltage drop
- Low leakage current
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, and polarity protection application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, D2PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

| MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted) | | | | | | |
|--|--------------|--------------------|-------------|------|--|--|
| PARAMETER | | | MBR10H100CT | UNIT | | |
| Maximum repetitive peak reverse voltage | | V_{RRM} | 100 | | | |
| Working peak reverse voltage | | | 100 | V | | |
| Maximum DC blocking voltage | | | 100 | | | |
| Maximum average forward rectified current at $T_C = 105$ °C | total device | - | 10 | _ | | |
| | per diode | I _{F(AV)} | 5.0 | | | |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode | | | 150 | Α | | |
| Peak repetitive reverse current per diode at $t_p = 2.0 \mu s$, 1 kHz | | | 0.5 | | | |
| Voltage rate of change (rated V _R) | | dV/dt | 10 000 | V/µs | | |
| Operating junction and storage temperature range | | | -65 to +175 | °C | | |
| Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min | | V _{AC} | 1500 | V | | |

MBR10H100CT, MBRF10H100CT, MBRB10H100CT

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| ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted) | | | | | | |
|---|-------------------------------|-----------------------|-------------------------|-------|------|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | | VALUE | UNIT | |
| Maximum instantaneous forward voltage per diode | V _F ⁽¹⁾ | I _F = 5 A | T _J = 25 °C | 0.76 | V | |
| | | I _F = 5 A | T _J = 125 °C | 0.61 | | |
| | | I _F = 10 A | T _J = 25 °C | 0.85 | | |
| | | I _F = 10 A | T _J = 125 °C | 0.71 | | |
| Maximum rayaraa ayyrant nar diada | I _R ⁽¹⁾ | Rated V _R | T _J = 25 °C | 3.5 | μΑ | |
| Maximum reverse current per diode | | | T _J = 100 °C | 4.5 | mA | |

Notes

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width ≤ 40 ms

| THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted) | | | | | |
|---|----------------|-----|------|------|------|
| PARAMETER | SYMBOL | MBR | MBRF | MBRB | UNIT |
| Typical thermal resistance per diode | $R_{	heta JC}$ | 2.2 | 5.2 | 2.2 | °C/W |

| ORDERING INFORMATION (Example) | | | | | | | |
|--------------------------------|--------------------|-----------------|--------------|---------------|---------------|--|--|
| PACKAGE | PREFERRED P/N | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE | | |
| TO-220AB | MBR10H100CT-E3/45 | 1.85 | 45 | 50/tube | Tube | | |
| ITO-220AB | MBRF10H100CT-E3/45 | 1.79 | 45 | 50/tube | Tube | | |
| TO-263AB | MBRB10H100CT-E3/45 | 1.35 | 45 | 50/tube | Tube | | |
| TO-263AB | MBRB10H100CT-E3/81 | 1.35 | 81 | 800/reel | Tape and reel | | |

RATINGS AND CHARACTERISTICS CURVES ($T_C = 25$ °C unless otherwise noted)

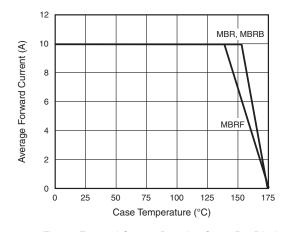


Fig. 1 - Forward Current Derating Curve Per Diode

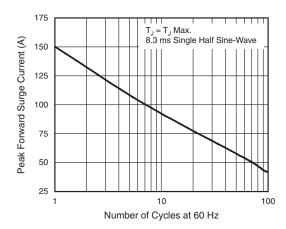


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode





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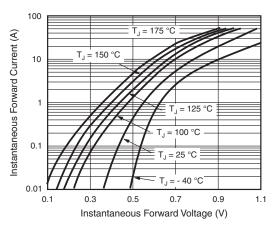


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

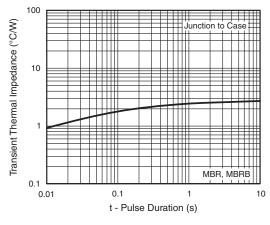


Fig. 6 - Typical Transient Thermal Impedance Per Diode

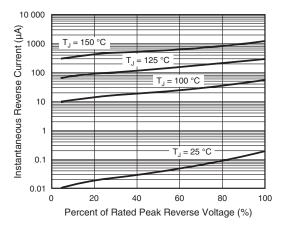


Fig. 4 - Typical Reverse Characteristics Per Diode

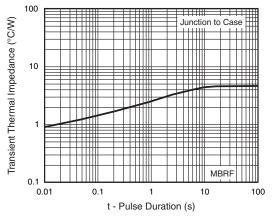


Fig. 7 - Typical Transient Thermal Impedance Per Diode

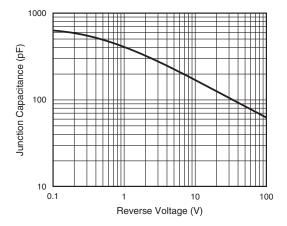


Fig. 5 - Typical Junction Capacitance Per Diode

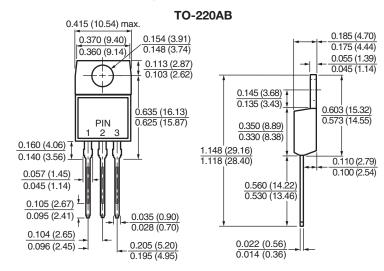


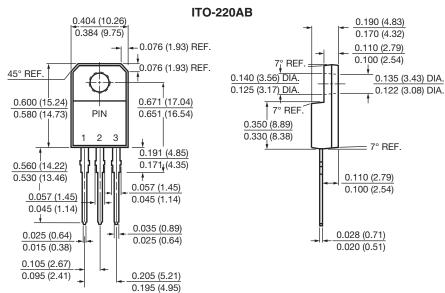


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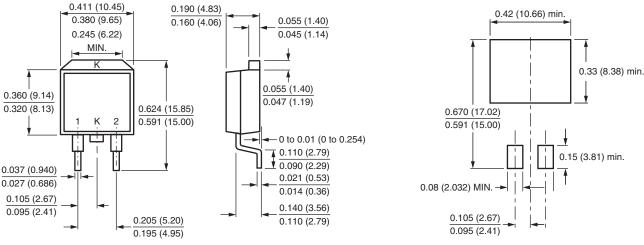
PACKAGE OUTLINE DIMENSIONS in inches (millimeters





D²PAK (TO-263AB)

Mounting Pad Layout



Revision: 08-Jun-2018 4 Document Number: 88668



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